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## BIB DATA SHEET

CONFIRMATION NO. 6431

<b>SERIAL NUMBER</b> 10/596,422	<b>FILING or 371(c) DATE</b> 06/13/2006 <b>RULE</b>	<b>CLASS</b> 438	<b>GROUP ART UNIT</b> 4176	<b>ATTORNEY DOCKET NO.</b> NL031497		
<b>APPLICANTS</b> Youri Ponomarev, Leuven, BELGIUM; <b>** CONTINUING DATA *****</b> This application is a 371 of PCT/IB04/52598 11/30/2004 <i>DW</i> <b>** FOREIGN APPLICATIONS *****</b> EUROPEAN PATENT OFFICE (EPO) 03104732.7 12/16/2003 <b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 04/11/2007						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and Acknowledged <u>/DANIEL B WHALEN/</u> Examiner's Signature		<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> BELGIUM	<b>SHEETS DRAWINGS</b> 2	<b>TOTAL CLAIMS</b> 10	<b>INDEPENDENT CLAIMS</b> 1
<b>ADDRESS</b> NXP, B.V. NXP INTELLECTUAL PROPERTY DEPARTMENT M/S41-SJ 1109 MCKAY DRIVE SAN JOSE, CA 95131 UNITED STATES						
<b>TITLE</b> Method for forming a strained si-channel in a mosfet structure						
<b>FILING FEE RECEIVED</b> 900	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit			